

1N1199(A,B)-1N1206(A,B)

SILICON POWER RECTIFIER

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

Parameter	Symbol	1N1199	1N1200	1N1201	1N1202	1N1203	1N1204	1N1205	1N1206
Peak reverse voltage	V_R	50V	100V	150V	200V	300V	400V	500V	600V
Operating & storage temperature range	T_J, T_{stg}	-65 to +200°C							
Maximum thermal resistance	$R_{\theta JC}$	2.5°C/W junction to case							
Mounting torque		25-30 inch pounds							
Weight		.16 ounces (5.0 grams) typical							

Add "R" to part numbers for reverse polarity.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Test Condition
Average forward current	$I_{F(AV)}$	12 Amps	$T_C = 170^\circ\text{C}$, half-sine wave, $R_{\theta JC} = 2.5^\circ\text{C/W}$
Maximum surge current	I_{FSM}	250 Amps	8.3ms, half-sine, $T_J = 200^\circ\text{C}$
Maximum I^2t for fusing	I^2t	260 A^2s	
Maximum peak forward voltage	V_{FM}	1.2 Volts	$I_{FM} = 30\text{A}$; $T_J = 25^\circ\text{C}^*$
Maximum peak reverse current	I_{RM}	10 μA	V_{RRM} , $T_J = 25^\circ\text{C}$
Maximum peak reverse current	I_{RM}	1.0 mA	V_{RRM} , $T_J = 150^\circ\text{C}^*$
Maximum recommended operating frequency		10 kHz	

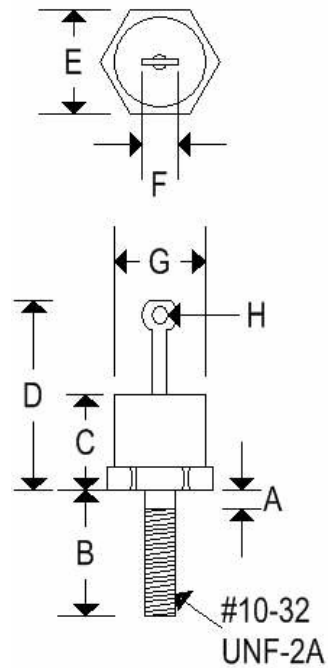
- Pulse test: pulse width 300 μsec . Duty cycle 2%

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MECHANICAL CHARACTERISTICS

Case	DO-4(R)
Marking	Alpha-numeric
Normal polarity	Cathode is stud
Reverse polarity	Anode is stud (add "R" suffix)



	DO-4(R)			
	Inches		Millimeters	
	Min	Max	Min	Max
A	-	0.078	-	1.981
B	0.422	0.453	10.719	11.506
C	-	0.405	-	10.287
D	-	0.800	-	20.320
E	0.420	0.440	10.668	11.176
F	-	0.250	-	6.350
G	-	0.424	-	10.770
H	0.066	-	1.676	-

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Figure 1
Typical Forward Characteristics

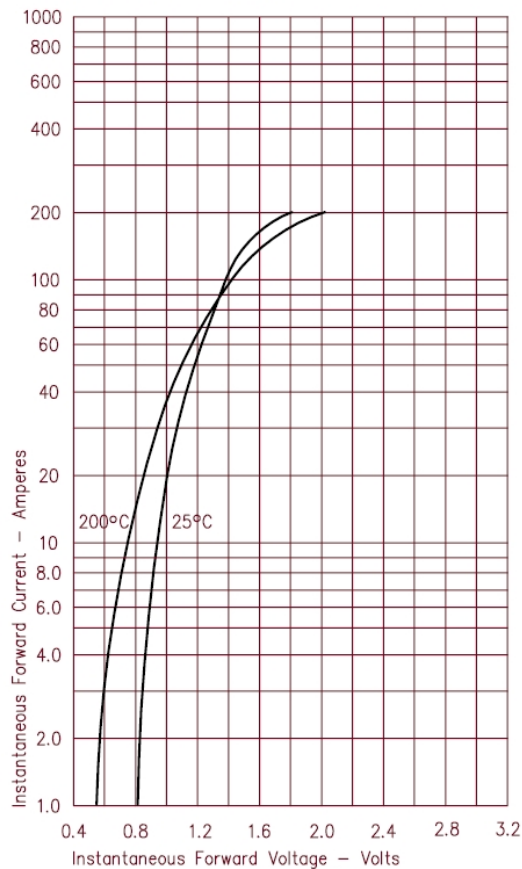


Figure 2
Typical Reverse Characteristics

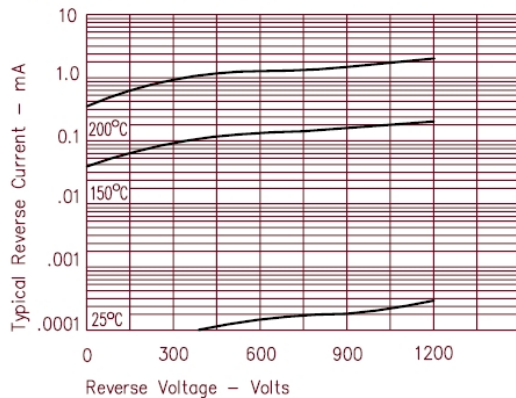


Figure 3
Forward Current Derating

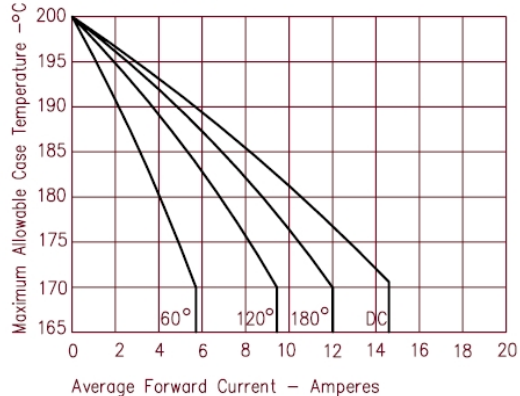


Figure 4
Maximum Forward Power Dissipation

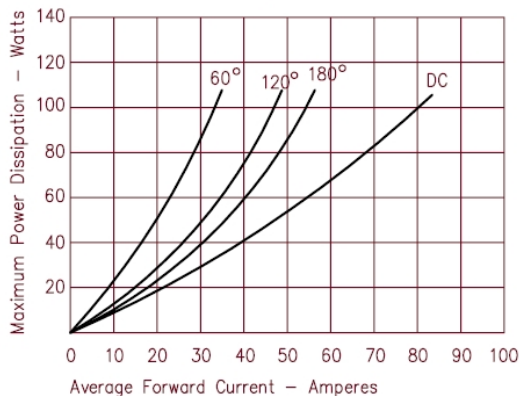


Figure 5
Transient Thermal Impedance

